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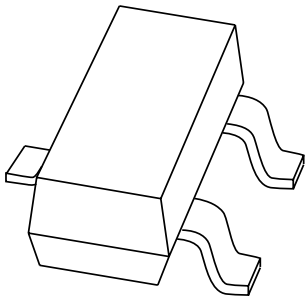
Kind regards,

Team Nexperia

DATA SHEET



PMBD353
Schottky barrier double diode

Product data sheet
Supersedes data of 1999 May 25

2001 Oct 15

Schottky barrier double diode PMBD353

FEATURES

- Low forward voltage
- Small SMD package
- Low capacitance.

APPLICATIONS

- UHF mixer
- Sampling circuits
- Modulators
- Phase detection.

DESCRIPTION

Planar Schottky barrier double diode in a SOT23 small plastic SMD package.

MARKING

TYPE NUMBER	MARKING CODE(1)
PMBD353	∗4F

Note

1. ∗ = p: Made in Hong Kong.
   ∗ = t: Made in Malaysia.
   ∗ = W: Made in China.

PINNING

PIN	DESCRIPTION
1	cathode k_1
2	anode a_2
3	common connection a_1, k_2

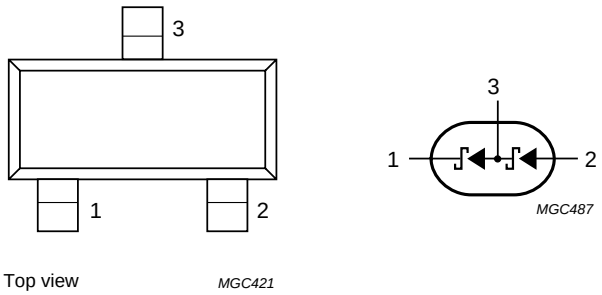


Fig.1 Simplified outline (SOT23) pin configuration and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Per diode				
V_R	continuous reverse voltage	–	4	V
I_F	continuous forward current	–	30	mA
T_{stg}	storage temperature	−65	+150	°C
T_j	junction temperature	–	100	°C

ELECTRICAL CHARACTERISTICS

T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
Per diode				
V_F	forward voltage	see Fig.2		
		I_F = 0.1 mA	350	mV
		I_F = 1 mA	450	mV
		I_F = 10 mA	600	mV
I_R	reverse current	V_R = 3 V; note 1; see Fig.3	0.25	μA
C_d	diode capacitance	f = 1 MHz; V_R = 0; see Fig.4	1	pF

Note

1. Pulse test: t_p = 300 μs; δ = 0.02.

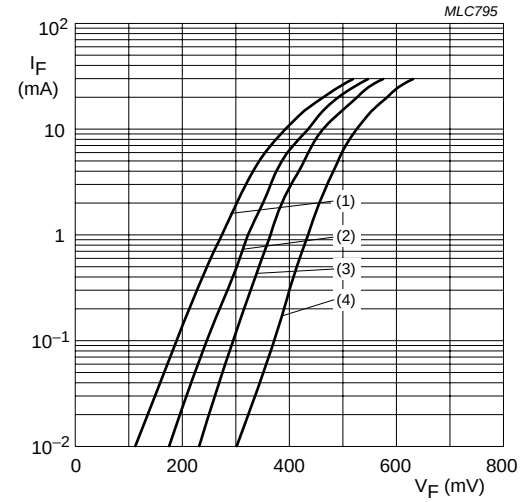
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-}a}$	thermal resistance from junction to ambient	note 1	500	K/W

Note

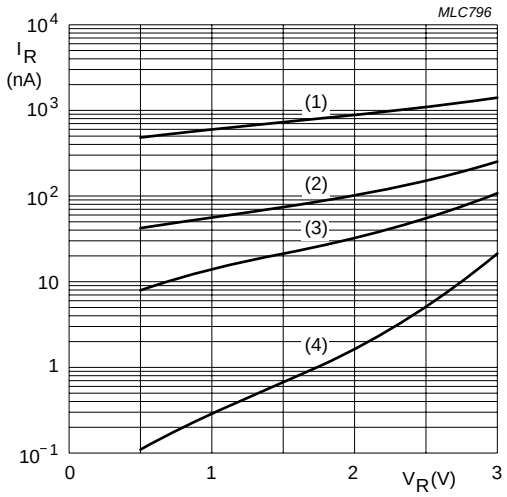
1. Refer to SOT23 standard mounting conditions.

GRAPHICAL DATA



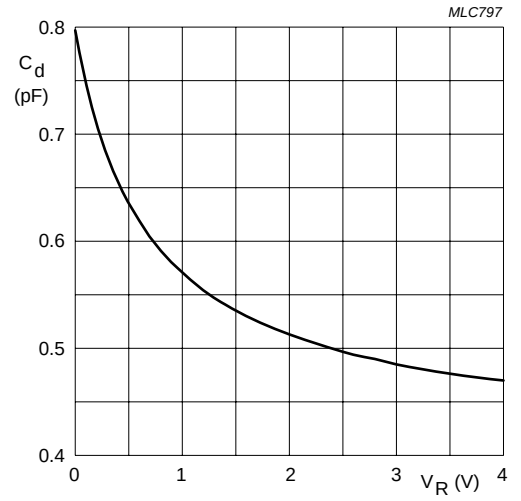
(1) T_{amb} = 100 °C.
(2) T_{amb} = 60 °C.
(3) T_{amb} = 25 °C.
(4) T_{amb} = −40 °C.

Fig.2 Forward current as a function of forward voltage; typical values.



(1) T_{amb} = 100 °C.
(2) T_{amb} = 60 °C.
(3) T_{amb} = 25 °C.
(4) T_{amb} = −40 °C.

Fig.3 Reverse current as a function of reverse voltage; typical values.

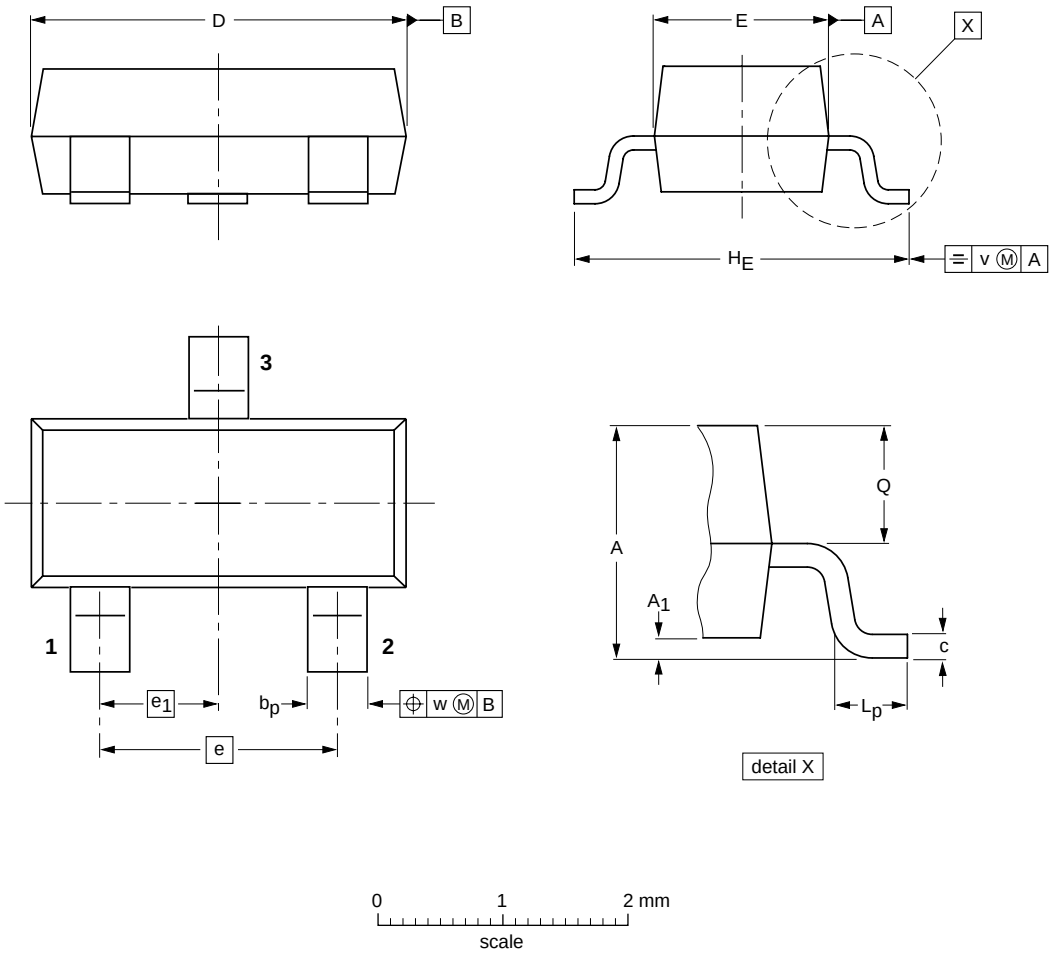


f = 1 MHz; T_{amb} = 25 °C.

Fig.4 Diode capacitance as a function of reverse voltage; typical values.

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads **SOT23**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1 max.	b_p	c	D	E	e	e_1	H_E	L_p	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT23		TO-236AB				~~97-02-28~~ 99-09-13

DATA SHEET STATUS

DOCUMENT STATUS[1]	PRODUCT STATUS[2]	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

1. Please consult the most recently issued document before initiating or completing a design.
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NXP Semiconductors

Customer notification

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